Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

Between 0.152 inches and 0.162 inches

Overall Diameter:

Between 0.115 inches and 0.125 inches

End Application:

Rcvr facsp anfsq-91

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

35.0 reverse voltage, instantaneous

Current Rating Per Characteristic:

10.00 microamperes forward current, average peak

Power Rating Per Characteristic:

400.0 milliwatts small-signal input power, common-collector absolute

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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